

# HD74LV1GT02A

## 2-input NOR Gate / CMOS Logic Level Shifter

REJ03D0116-0900 Rev.9.00 Mar 21, 2008

## **Description**

The HD74LV1GT02A is high-speed CMOS two input NOR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output. The input protection circuitry on this device allows over voltage tolerance on the input, allowing the device to be used as a logic-level translator from 3.0 V CMOS Logic to 5.0 V CMOS Logic or from 1.8 V CMOS logic to 3.0 V CMOS Logic while operating at the high-voltage power supply. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

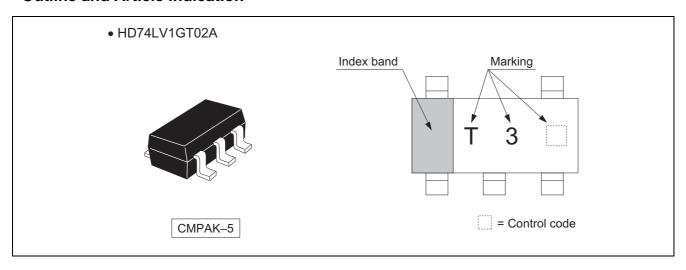
### **Features**

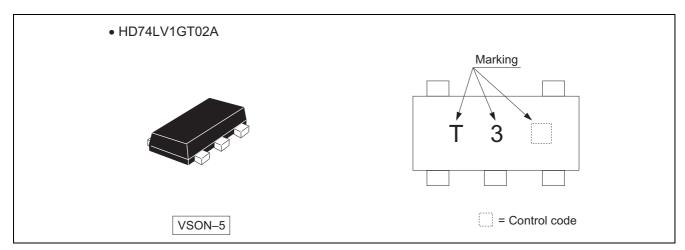
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- TTL compatible input level.
  - Supply voltage range: 3.0 to 5.5 V
  - Operating temperature range : -40 to +85°C
- Logic-level translate function
  - 3.0 V CMOS logic  $\rightarrow$  5.0 V CMOS logic (@V<sub>CC</sub> = 5.0 V)
  - 1.8 V or 2.5 V CMOS logic  $\rightarrow$  3.3 V CMOS logic (@V<sub>CC</sub> = 3.3 V)
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
  - All outputs  $V_0$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V)
- Output current  $\pm 6 \text{ mA}$  (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 12 \text{ mA}$  (@V<sub>CC</sub> = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Pookogo Typo	Package Code Package Package Type		Taping Abbreviation	
Part Name	(Previous Code)		Abbreviation	(Quantity)	
HD74LV1GT02ACME	CMPAK-5 pin	PTSP0005ZC-A	CM	E (3000 pcs/reel)	
TID74EV TOTOZACIVIL	OMI AN-3 pin	(CMPAK-5V)	Civi	E (3000 pcs/reel)	
LIDZAL VACTOSAVCE	VCON F nin	PUSN0005KA-A	\/C	F (2000 peo/reel)	
HD74LV1GT02AVSE	VSON-5 pin	(TNP-5DV)	VS	E (3000 pcs/reel)	

Note: Please consult the sales office for the above package availability.

## **Outline and Article Indication**



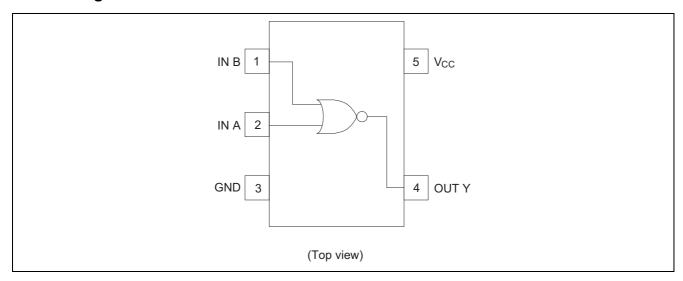


## **Function Table**

In	Quitnut V	
A	В	Output Y
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

H : High level L : Low level

## **Pin Arrangement**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to 7.0	V	
Output voltage range *1, 2	V	-0.5 to V <sub>CC</sub> + 0.5	V	Output : H or L
Output voltage range	Vo	-0.5 to 7.0	V	V <sub>CC</sub> : OFF
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>I</sub> < 0
Output clamp current	I <sub>OK</sub>	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I <sub>O</sub>	±25	mA	$V_O = 0$ to $V_{CC}$
Continuous current through V <sub>CC</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P <sub>T</sub>	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

## **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	3.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	Vcc	V	
	I <sub>OL</sub>	_	6		V <sub>CC</sub> = 3.0 to 3.6 V
Outrot summent		_	12		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Output current	I <sub>OH</sub>	_	-6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt / Δv	0	100	ns / V	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
Input transition rise or fall rate	Δι / Δν	0	20	] 115 / V	V <sub>CC</sub> = 4.5 to 5.5 V
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

## **Electrical Characteristic**

### • $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V <sub>CC</sub> (V) *	Min	Тур	Max	Unit	Test condition
	V <sub>IH</sub>	3.0 to 3.6	1.5	_	_		
Input voltage	VIH	4.5 to 5.5	2.0	_	_	V	
input voitage	V <sub>IL</sub>	3.0 to 3.6	_	_	0.6	V	
	V IL	4.5 to 5.5	_	_	0.8		
Hysteresis voltage	V	3.3	_	0.10	_	V	$V_T^+ - V_T^-$
Hysteresis voitage	V <sub>H</sub>	5.0	_	0.15	_	ľ	VT - VT
		Min to Max	V <sub>CC</sub> -0.1	_	_		$I_{OH} = -50 \mu A$
	V <sub>OH</sub>	3.0	2.48	_	_		$I_{OH} = -6 \text{ mA}$
Output voltage		4.5	3.8	_	_	V	$I_{OH} = -12 \text{ mA}$
Output voltage	V <sub>OL</sub>	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		3.0	_	_	0.44		$I_{OL} = 6 \text{ mA}$
		4.5	_	_	0.55		I <sub>OL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	V <sub>IN</sub> = 5.5 V or GND
Quiescent	1	5.5			10	^	$V_{IN} = V_{CC}$ or GND,
supply current	I <sub>CC</sub>	5.5			10	μΑ	$I_{O} = 0$
	$\Delta I_{CC}$	5.5	_	_	1.5	mA	One input $V_{IN} = 3.4 \text{ V}$ ,
	∆i(()	0.0			1.0	111/4	other input V <sub>CC</sub> or GND
Output leakage current	I <sub>OFF</sub>	0	_	_	5	μΑ	$V_{IN}$ or $V_O = 0$ to 5.5 V
Input capacitance	$C_{IN}$	5.0	_	2.5	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

## **Switching Characteristics**

•  $V_{CC} = 3.3 \pm 0.3 \text{ V}$ 

Item	Symbol	Ta = 25°C			Ta = -40	to 85°C	Unit	Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Onit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>		7.0	11.0	1.0	13.0	nc	$C_L = 15  pF$	A or B	V
delay time	t <sub>PHL</sub>	_	9.0	14.0	1.0	15.5	ns	$C_L = 50 pF$	AUID	'

 $\bullet \quad V_{CC} = 5.0 \pm 0.5 \ V$ 

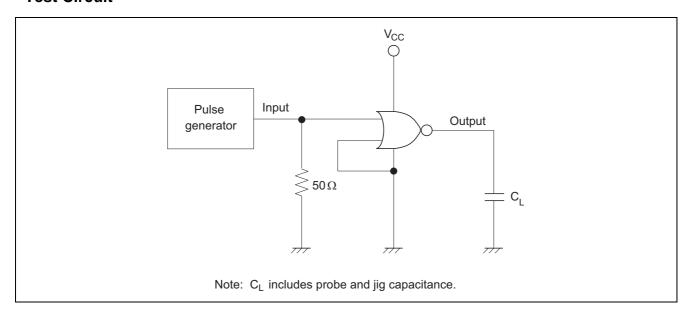
Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test	FROM	ТО
iteiii	Syllibol	Min	Тур	Max	Min	Max	Onit	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>		5.0	6.2	1.0	7.5	ns	$C_L = 15  pF$	A or B	V
delay time	t <sub>PHL</sub>		6.5	9.0	1.0	10.0		$C_L = 50 pF$	7 01 15	Į.

## **Operating Characteristics**

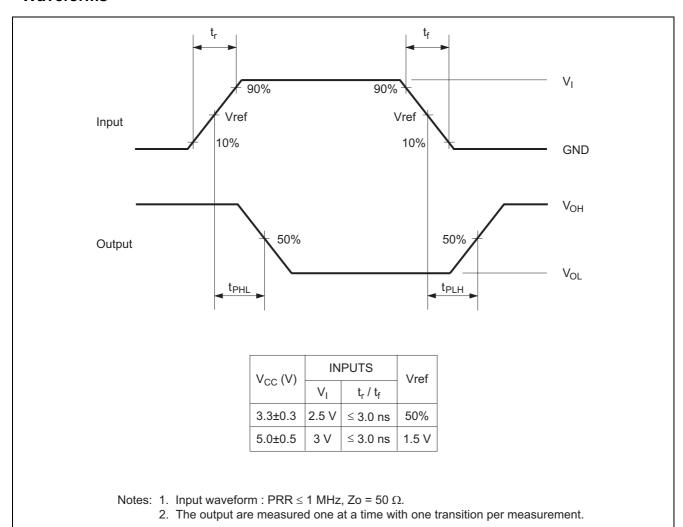
•  $C_L = 50 \text{ pF}$ 

Item	Symbol	Symbol V <sub>cc</sub> (V)		T <sub>a</sub> = 25°C			Test Conditions	
iteiii	Syllibol	ACC (A)	Min	Тур	Max	Unit	rest conditions	
Power dissipation capacitance	C <sub>PD</sub>	5.0		10.3	_	pF	f = 10 MHz	

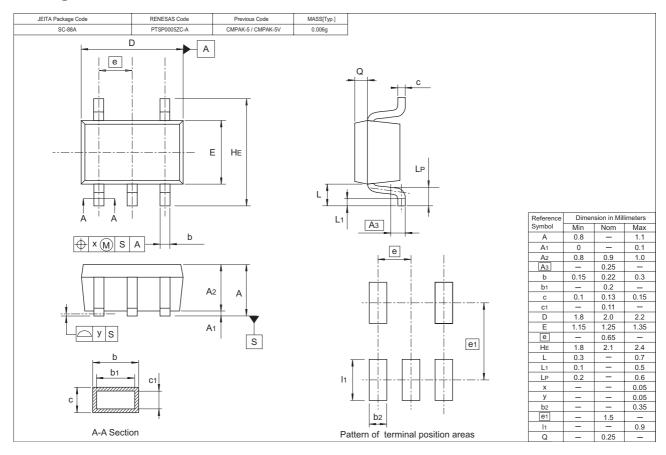
## **Test Circuit**

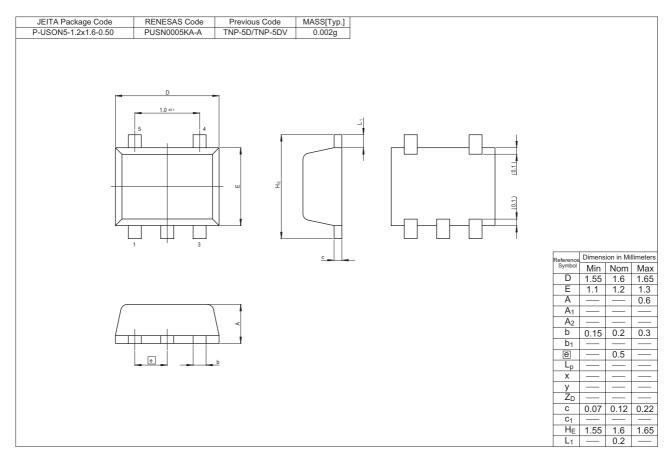


## **Waveforms**



## **Package Dimensions**





Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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### Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

**Renesas Technology Taiwan Co., Ltd.** 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510